

CMOS LOW VOLTAGE, LOW CHARGE INJECTION QUAD SPST ANALOG SWITCHES

GENERAL DESCRIPTION

The ALD4201/ALD4202M are quad SPST CMOS analog switches specifically developed for 3 to 12 volt applications where low charge injection and low leakage currents are important analog switch operating characteristics. The main features are precision matching, charge compensation circuitry, fast switching, low on-resistance and micropower consumption. The ALD4201 operates in break-before-make switching whereas the ALD4202M operates in make-before-break switching.

The ALD4201/ALD4202M are designed for precision applications such as charge amplifiers, sample and hold amplifiers, data converter switches, and programmable gain amplifiers. These switches are also excellent for general purpose switching applications for micropower battery operated systems.

APPLICATIONS INFORMATION

The ALD4201/ALD4202M are designed to operate with standard single or dual power supplies of +3V to 10V or $\pm 1.5V$ to $\pm 5V$. Functionality extends down to +2V or $\pm 1V$ power supply, making it suitable for lithium battery or rechargeable battery operated systems where power efficiency and performance are important design parameters. These switches feature nA quiescent current and interface directly to CMOS logic levels from microprocessor or logic interface circuits. Built- in level shifters at the input stage provide for dual supply analog signal switching. On the board level, low charge injection and fast operation can be obtained by using short leads, minimizing input and output capacitances, and by adequate bypass capacitors placed on the board at the supply nodes. For more information, see Application Note AN4200.

The ALD4201/4202M are manufactured with Advanced Linear Devices' enhanced ACMOS silicon gate CMOS process, and are also part of the linear elements in Advanced Linear Devices' "Function-Specific" ASIC.

ORDERING INFORMATION

Оре	Operating Temperature Range									
-55°C to +125°C	0°C to +70°C	0°C to +70°C								
16-Pin	16-Pin	16-Pin								
CERDIP	Plastic Dip	SOIC								
Package	Package	Package								
ALD4201 DC	ALD4201 PC	ALD4201 SC								
ALD4202M DC	ALD4202M PC	ALD4202M SC								

LOGIC TABLE

Input Logic	Switch State						
mpat Logio	ALD4201	ALD4202M					
0 1	On Off	Off On					

^{*} Contact factory for industrial temperature range.

FEATURES

- 3V, 5V & 10V supply operation
- ±1.5V, ±2.5V & ±5V supply operation
- 0.1μW power dissipation
- 1pC charge injection
- Rail-to-rail signal range
- · Low on-resistance
- pA leakage current
- 4201 break-before-make switching
- 4202M make-before-break switching
- Built-in dual supply level translator

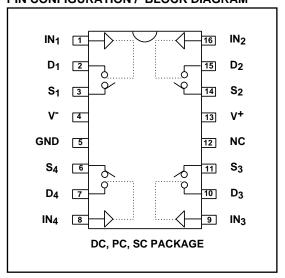
BENEFITS

- · Fast effective signal throughput
- Low switching transients
- Low signal loss
- Essentially no DC power consumption
- Full analog signal range over power supply rail
- Flexible power supply range for battery operated systems

APPLICATIONS

- Low level signal conditioning circuits
- Portable battery operated instruments
- Computer peripherals
- PCMCIA
- · Fast sample and hold
- Analog signal multiplexer
- Programmable gain amplifiers
- Switched capacitor circuits
- Micropower based systems
- Video/audio switches
- Feedback control systems

PIN CONFIGURATION / BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Supply voltage, V+ referenced to V-	-0.3V to +13.2V -0.3V to +13.2V
Terminal voltage range (any terminal) Note 1	***************************************
Power dissipation	, , , ,
Operating temperature range PC, SC package	0°C to +70°C
DC package —	-55°C to +125°C
Storage temperature range	65°C to +150°C
Lead temperature, 10 seconds	+260°C
DC current (any terminal)	10mA

POWER SUPPLY RANGE

		4201/	/4202M (PC	C,SC)	42	01/4202M (DC)		
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	
Supply Voltage	V _{SUPPLY}	±1.5 3.0		±6.0 12.0	±1.5 3.0		±6.0 12.0	V V	Dual Supply Single Supply

DC ELECTRICAL CHARACTERISTICS

$T_A = 25$ °C V+ = +5.0V, V- = -5.0V GND = 0.0V unless otherwise specified

		4201	/4202M (P	C,SC)	42	01/4202M (DC)		
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Analog Signal Range	VA	-5.0		5.0	-5.0		5.0	V	
On - Resistance	R _{ON}		90 120	135 180		90 140	135 210	Ω	V _A = 0V I _A = 1mA 0°C to +70°C -55°C to +125°C
Change of On-Resistance from -V _S to +V _S	ΔR _{ON}		16			16		%	
Change of On-Resistance with Temperature	ΔR _{ON} /ΔΤ		0.43			0.43		%/°C	
R _{ON} Match Between Switches			2			2		%	
Source Off Leakage Current	IS(OFF)		50	100 500		50	100 4000	pA pA pA	$V_S = +/-4.0V$, $V_D = -/+4.0V$ 0°C to +70°C -55°C to +125°C
Drain Off Leakage Current	ID(OFF)		50	100 500		50	100 4000	pA pA pA	V _D = +/-4.0V, V _S = -/+4.0V 0°C to +70°C -55°C to +125°C
Channel On Leakage Current	I _{D(ON)}		50	100 500		50	100 4000	pA pA pA	0°C to +70°C -55°C to +125°C
Input High Voltage	V _{IH}	4.0			4.0				Logic "1"
Input Low Voltage	V _{IL}			0.8			0.8	V	Logic "0"
Input High or Input Low Current	I _{IH} I _{IL}			10			10	nA	±1.5 ≤ V _{SUPPLY} ≤ ±5.0V
Supply Current	ISUPPLY	_	0.01	1		0.01	1	μА	

AC ELECTRICAL CHARACTERISTICS

$T_A = 25^{\circ}C$ V+ = +5.0V, V- = -5.0V, GND = 0.0V unless otherwise specified

		4201	1/4202M	(PC)	4201	/4202M	(DC)	4201/4202M (SC)				
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Turn On Delay time	t _{ON}		150 60	240 110		150 60	240 110		150 60	240 110	ns ns	4201 (Note 2) 4202M
Turn Off Delay time	tOFF		60 100	130 180		60 100	130 180		60 100	130 180	ns ns	4201 (Note 2) 4202M
Break-Before-Make Delay Time	t _{BD}	20	90		20	90		20	90		ns	4201 (Note 3)
Make-Before-Break Delay Time	t _{MD}	15	40		15	40		15	40		ns	4202M (Note 3)
Charge Injection	Q _{INJ}		2 1	5 2.5		2 1	5 2.5		1 0.7	2.5 2.0	pC pC	4201 (Note 3) (Note 4) 4202M
Off Isolation			75			75			75		dB	At f = 100KHz, (Note 5)
Crosstalk			90			90			90		dB	At f = 100KHz, (Note 6)
Total Harmonic Distortion	T _{HD}		0.05 0.01			0.05 0.01			0.05 0.01		%	R _L = 10K R _L = 100K
Source/Drain Off Capacitance	C _{S(OFF)} C _{D(OFF)}		3.0			3.0			3.0		pF	
Channel On Capacitance	C _{DS(ON)}		5.7			5.7			5.7		pF	
Pin to Pin Capacitance	СРР		0.5			0.6			0.25		pF	

DC ELECTRICAL CHARACTERISTICS

$T_A = 25^{\circ}C \text{ V+=} +5.0 \text{V}, \text{ V-} = \text{GND} = 0.0 \text{V}$ unless otherwise specified

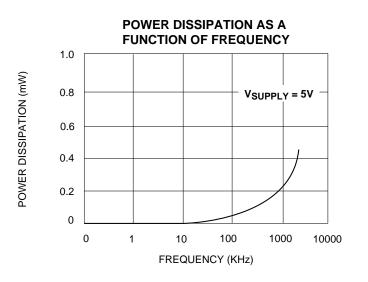
		ALD4	201/4202N	I (PC,SC)	ALD	4201/4202M	(DC)		
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Analog Signal Range	VA	0.0		+5.0	0.0		+5.0	V	
On - Resistance	R _{ON}		195 240	280 350		195 270	280 390	Ω	V _A = +2.5V I _A = 1mA 0°C to +70°C -55°C to +125°C
Change of On-Resistance from -Vs to +Vs	ΔR _{ON}		20			20		%	
Change of On-Resistance with Temperature	ΔR _{ON} /ΔΤ		0.43			0.43		%/°C	
R _{ON} Match Between Switches			2			2		%	
Input High Voltage	V _{IH}	4.0			4.0			V	
Input Low Voltage	V _{IL}			0.8			0.8	V	

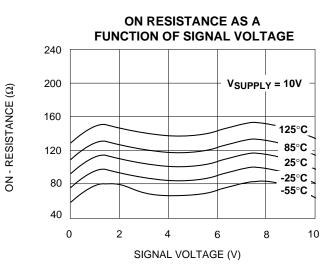
^{1.} Voltage on any terminal must be less than (V+) + 0.3V and greater than (V-) - 0.3V, at all times including before power is applied and V+ = V- = 0.0V. Vsupply power supply needs to be sequenced on first on power turn-on and sequenced off last during power turn-off. 2. See Switching Time Test Circuit. 3. Guaranteed by design . 4. See Charge Injection Test Circuit 5. See Off Isolation Test Circuit 6. See Crosstalk Test Circuit

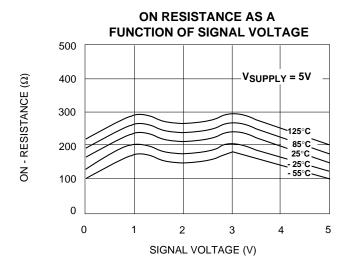
DC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C \text{ V+} = +3.0V, V^{-} = \text{GND} = 0.0V \text{ unless otherwise specified}$

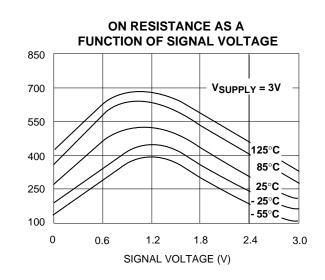
		4201/4202M (PC,SC)			4201	/4202M (DC	;)		
Parameter	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
Analog Signal Range	VA	0.0		3.0	0.0		3.0	V	
On - Resistance	R _{ON}		500 620	700 880		500 680	700 1000	Ω	V _A = 1.5V I _A = 1mA 0°C to +70°C -55°C to +125°C
Change of On-Resistance from -V _S to +V _S	ΔR _{ON}		43			43		%	
Change of On-Resistance with Temperature	ΔR _{ON} /ΔΤ		0.27			0.27		%/°C	
R _{ON} Match Between Switches			2			2		%	
Input High Voltage	V _{IH}	2.4			2.4			V	
Input Low Voltage	V _{IL}			0.8			0.8	V	

TYPICAL PERFORMANCE CHARACTERISTICS



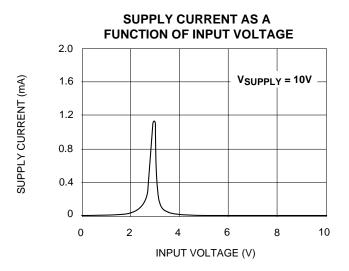


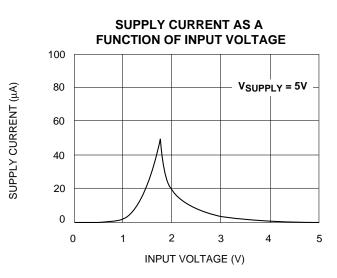


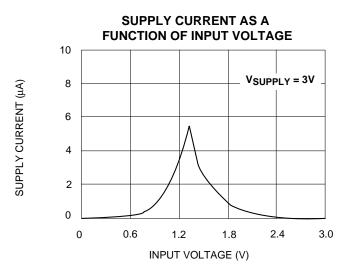


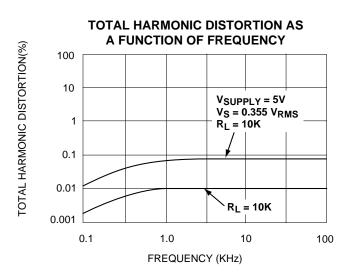
ON - RESISTANCE (Ω)

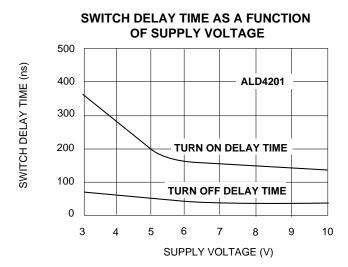
TYPICAL PERFORMANCE CHARACTERISTICS

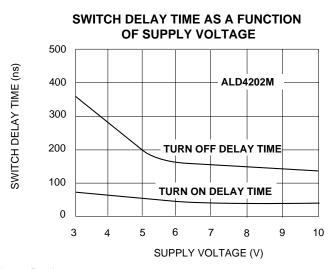






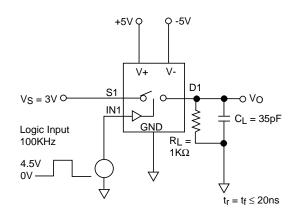


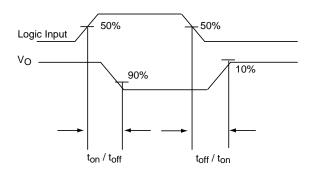




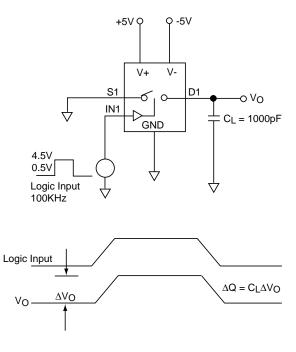
TEST CIRCUITS

SWITCHING TIME TEST CIRCUIT

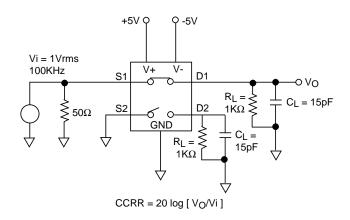




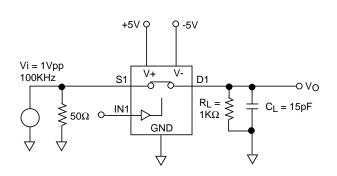
CHARGE INJECTION TEST CIRCUIT



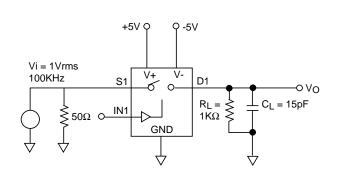
CROSSTALK TEST CIRCUIT



TOTAL HARMONIC DISTORTION TEST CIRCUIT



OFF ISOLATION TEST CIRCUIT



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PI5A4157ZUEX PI5A3166TAEX FSA634UCX TC4066BP(N,F) DG302BDJ-E3 PI5A100QEX HV2605FG-G HV2301FG-G
RS2117YUTQK10 RS2118YUTQK10 RS2227XUTQK10 ADG452BRZ-REEL7 MAX4066ESD+ MAX391CPE+ MAX4730EXT+T
MAX314CPE+ BU4066BCFV-E2 MAX313CPE+ BU4S66G2-TR NLAS3158MNR2G NLASB3157MTR2G TS3A4751PWR
NLAS4157DFT2G NLAS4599DFT2G NLASB3157DFT2G NLAST4599DFT2G NLAST4599DTT1G DG300BDJ-E3 DG2503DB-T2-GE1
DG2502DB-T2-GE1 TC4W53FU(TE12L,F) 74HC2G66DC.125 ADG619BRMZ-REEL ADG1611BRUZ-REEL7 LTC201ACN#PBF